

2-Gbps DIFFERENTIAL SWITCH 8-Bit, 1:2 MULTIPLEXER/DEMULTIPLEXER WITH 3-SIDE BAND SIGNALS

Check for Samples: TS3DV20812

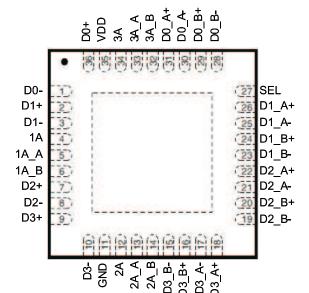
FEATURES

- Four High-Speed Bidirectional Differential Pair Channel MUX/DEMUX
- Supports up to 2 Gbps Data Rate
- V_{DD} Operating Range 2.5 V or 3.3
 - 0 V to 3.3 V Rail To Rail at 2.5 V
 - -0 V to 5 V Rail To Rail at 3.3V
- I_{OFF} partial Powerdown and Back-Drive Protection.
- 5-V Input Tolerant on Control Pin
- Supports Both AC- and DC-Coupled Signals
- Low Crosstalk: -38 dB at 825 MHz, 2.5 V or 3.3 V
- Insertion Loss: -1.5 dB at 825 MHz, 2.5 V or 3.3 V
- Off Isolation -24.67 dB at 825 MHz
- Low Bit-to-Bit Skew within Pair 5 ps Maximum
- Channel-to-Channel Skew: 30 ps Maximum
- Propagation Delay Times: 250 ps Maximum
- ESD Performance Tested per JESD 22
 - 2000-V Human Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

APPLICATIONS

- HDMI/DVI Video MUX
- Panel LVDS Bus MUX
- LVDS, LVPECL, CML
- Analog Signals VGA
- Gigabit LAN Signal MUX
- Serial Backplane Signal MUX
- Optical Module
- Central Office Telecommunication
- Wireless Base Station
- High-Speed Logic Data I/O MUX





DESCRIPTION/ORDERING INFORMATION

TS3DV20812 is a High Speed Data Rate up to 2Gbps for Differential Signal Passive bi-directional Multiplexer and De-multiplexer for I/O rails up to 5V Level with Low Crosstalk and Insertion Loss.

TS3DV20812 can be used in either HDMI/DVI sink side or source side with 4-differential pair supporting the high speed and control pins.

The loff and back drive protection allowing to connect the external cable and prevent the back flow current when the Vcc is into 0V.

The 3 side band signals can be used in DDC (SDAL, SCL) and CEC Signal MUX.

TS3DS20812 is characterized for operation from -40C to 85C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

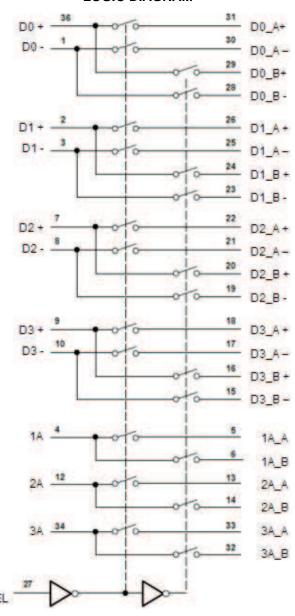


Table 1. ORDERING INFORMATION

| T _A | PACKAGE ⁽¹⁾ (2) | | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|----------------------------|---------------|-----------------------|------------------|
| -40°C to 85°C | QFN – RHH | Tape and reel | TS3DV20812RHH | TBD |

- Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
 For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

LOGIC DIAGRAM



FUNCTION TABLE

| INPUT | DIFFERENTIAL | FUNCTIONS | | |
|-------|----------------------|---------------------|---------------------|--|
| SEL | SIGNAL I/Os | A-PORT | B-PORT | |
| L | Dn (±), nA (AUX (±), | DnA (±), nA_A | High-impedance mode | |
| Н | HPD, CAD/CEC) | High-impedance mode | DnB (±), nA_B | |



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------|---|---------------------------------------|------|-----------------------|----------|
| V_{DD} | Supply voltage range | | -0.5 | 4.6 | V |
| V_{IN} | Control input voltage range ⁽²⁾⁽³⁾ | SEL | -0.5 | 7 | V |
| | | I/O | -0.5 | 7 | V |
| V _{IO} | Switch I/O voltage range (all three I/O ports) ⁽⁴⁾ | D0-D3, Aux, HPD, CAD/CEC | -0.5 | V _{CC} + 0.5 | V |
| | | A port and B port | -0.5 | $V_{CC} + 0.5$ | V |
| I_{IK} | Control input clamp current | V _{IN} < 0 | | - 50 | mA |
| I _{I/OK} | I/O port clamp current | V _O < 0 | | -50 | mA |
| I _{IO} | Continuous output current (5) | ON-state switch | | ±128 | mA |
| | Continuous current through VDD or GND | | | ±100 | mA |
| Θ_{JA} | Package thermal impedance (6) | RHH package | | 31.8 | °C/W |
| T _{stg} | Storage temperature range | · · · · · · · · · · · · · · · · · · · | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

| | | | MIN | MAX | UNIT |
|---------------------|----------------------------------|---------------------------|------|----------|------|
| V_{DD} | Supply voltage | | 2.25 | 3. 6 | V |
| V_{IH} | High-level control input voltage | SEL | 2 | 5.5 | V |
| V_{IL} | Low-level control input voltage | SEL | 0 | 0.8 | V |
| V _{I/O} | Input/output voltage | All ports | 0 | 5.5 | V |
| V _{ANALOG} | Analog signal range | Differential signal range | 0 | V_{DD} | V |
| VI | Input tolerant | SEL | 0 | 5.5 | V |
| T _A | Operating free-air temperature | | -40 | 85 | °C |

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All voltages are with respect to ground, unless otherwise specified.

The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

⁽⁴⁾ V_I and V_O are used to denote specific conditions for V_{IO}.

⁽⁵⁾

 $I_{\rm l}$ and $I_{\rm O}$ are used to denote specific conditions for $I_{\rm lO}$. The package thermal impedance is calculated in accordance with JESD 51-7.



ELECTRICAL CHARACTERISTICS

for high-frequency switching over recommended operating free-air temperature range V_{DD} = 3.3 V \pm 0.3 V (unless otherwise noted)

| PARAMETER | | | TEST CONDITIONS ⁽¹⁾ | | | TYP ⁽²⁾ | MAX | TINU |
|----------------------------|--------|---------------------------|---|-------------------------------|--|--------------------|------|------|
| V _{IK} | SEL | $V_{DD} = 3.6 V,$ | I _{IN} = -18 mA | | | -0.7 | -1.2 | V |
| I _{IH} | SEL | $V_{DD} = 3.6 V,$ | $V_{IN} = V_{DD}$ | | | | ±1 | μΑ |
| I _{IL} | SEL | $V_{DD} = 3.6 V,$ | $V_{IN} = GND$ | | | | ±1 | μА |
| I _{OFF} | • | $V_{DD} = 06 V$, | $V_O = 0$ to 3.6 V , | $V_I = 0$, $V_{IN} = 0$ | | | 1 | μА |
| I _{CC} | | $V_{DD} = 3.6 \text{ V},$ | I _{IO} = 0 | Switch ON or OFF | | 250 | 500 | μА |
| C _{IN} | SEL | f = 10 MHz , | $V_{IN} = 0$ | | | 2 | 2.5 | pF |
| C _{OFF} | 3-Port | f = 10 MHz , | $V_{IN} = 0$, | Output is Open, Switch is OFF | | 2.5 | 4 | pF |
| C _{ON} | 3-Port | f = 10 MHz , | V _{IN} = 0 , | Output is Open, Switch is ON | | 8 | | pF |
| r _{ON} | | V _{DD} = 3.6 V | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$ | $I_O = -40 \text{ mA}$ | | 4 | 6 | Ω |
| r _{ON(flat)} | 3) | V _{DD} = 3.6 V | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$ | $I_O = -40 \text{ mA}$ | | 0.5 | | Ω |
| $\Delta \; r_{ON}{}^{(4)}$ | | V _{DD} = 3.6 V | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$ | $I_O = -40 \text{ mA}$ | | 0.4 | 1 | Ω |

- $\begin{array}{lll} \hbox{(1)} & V_I, \ V_O, \ I_I, \ \text{and} \ I_O \ \text{refer} \ \text{to} \ I/O \ \text{pins}, \ V_{IN} \ \text{refers} \ \text{to} \ \text{the control inputs}. \\ \hbox{(2)} & All \ \text{typical values} \ \text{are} \ \text{at} \ V_{DD} = 3.3 \ \text{V} \ \text{(unless otherwise noted)}, \ T_A = 25^\circ. \\ \hbox{(3)} & r_{ON} \ \text{(flat)} \ \text{is} \ \text{the} \ \text{difference} \ \text{of} \ r_{ON} \ \text{in} \ \text{a} \ \text{given channel} \ \text{at} \ \text{specified voltages}. \\ \hbox{(4)} & \Delta r_{ON} \ \text{is} \ \text{the} \ \text{difference} \ \text{of} \ r_{ON} \ \text{from center} \ \text{(D0 to Dn)} \ \text{ports} \ \text{to} \ \text{any} \ \text{other port}. \\ \end{array}$

ELECTRICAL CHARACTERISTICS

for high-frequency switching over recommended operating free-air temperature range V_{DD} = 2.5 V ± 0.25 V (unless otherwise noted)

| PAF | RAMETER | | TEST CONDITIO | NS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT |
|----------------------------|---------|---------------------------|---|-------------------------------|-----|--------------------|------|------|
| V _{IK} | SEL | V _{DD} = 2.5 V , | I _{IN} = -18 mA | | | -0.7 | -1.2 | V |
| I _{IH} | SEL | $V_{DD} = 2.5 V$, | $V_{IN} = V_{DD}$ | | | | ±1 | μΑ |
| I _{IL} | SEL | $V_{DD} = 2.5 V$, | $V_{IN} = GND$ | | | | ±1 | μΑ |
| I _{OFF} | | V _{DD} = 06 V, | $V_0 = 0 \text{ to } 2.5 \text{ V}$, | $V_I = 0$, $V_{IN} = 0$ | | | 1 | μА |
| I _{CC} | | $V_{DD} = 2.5 V$, | $I_{IO} = 0$ | Switch ON or OFF | | 250 | 500 | μΑ |
| C _{IN} | SEL | f = 10 MHz , | $V_{IN} = 0$ | | | 2 | 2.5 | pF |
| C _{OFF} | 3-Port | f = 10 MHz , | $V_{IN} = 0$, | Output is Open, Switch is OFF | | 2.5 | 4 | pF |
| C _{ON} | 3-Port | f = 10 MHz , | $V_{IN} = 0$, | Output is Open, Switch is ON | | 8 | | pF |
| r _{ON} | | V _{DD} = 2.5 V | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$ | $I_O = -40 \text{ mA}$ | | 4 | 6 | Ω |
| r _{ON(flat)} (3 | 3) | V _{DD} = 2.5 V | $V_I = 1.5 \text{ V} \text{ and } V_{DD}$ | $I_O = -40 \text{ mA}$ | | 0.5 | | Ω |
| $\Delta \; r_{ON}{}^{(4)}$ | | $V_{DD} = 2.5 \text{ V}$ | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$ | $I_O = -40 \text{ mA}$ | | 0.4 | 1 | Ω |

- V_I , V_O , I_I , and I_O refer to I/O pins, V_{IN} refers to the control inputs. All typical values are at $V_{DD} = 2.5 \text{ V}$ (unless otherwise noted), $T_A = 25^\circ$. r_{ON} (flat) is the difference of r_{ON} in a given channel at specified voltages.
- Δr_{ON} is the difference of r_{ON} from center (D0 to Dn) ports to any other port.

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{DD} = 3.3 \text{ V} \pm 0.3 \text{ V}$, $R_L = 200 \Omega$, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 9 and Figure 10)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|-------------------------------------|-----------------|----------------------------------|-----|--------------------|-----|------|
| t _{pd} ⁽²⁾ | Dn | D _A or D _B | | 149 | | ps |
| t _{PZH} , t _{PZL} | SEL | D _A or D _B | 0.5 | | 15 | ns |
| t _{PHZ} , t _{PLZ} | SEL | D _A or D _B | 0.9 | | 12 | ns |
| SEL to switch turn on time | | D _A or D _B | | 9 | 14 | ns |
| SEL to switch turn off time | | D _A or D _B | | 5 | 11 | ns |
| t _{sk(o)} (3) | Dn (+)(-), DA | Dn (+)(-), DA(+)(-), DB(+)(-) | | 22 | 28 | ps |
| t _{sk(o)} | Dn (all), DnA | A(all), DnB(All) | | 19 | 25 | ps |
| t _{sk(p)} (4) | | | | 22 | 31 | ps |

- All typical values are at V_{DD} = 2.5 V (unless otherwise noted), T_A = 25°.
- The propagation delay is the calculated RC time constant of the typical ON-State resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
- Output skew between center port to any other port.
- Skew between opposite transitions of the same output in a given device |t_{PHL} t_{PLH}|

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 2.5V ± 0.25 V, R_L = 200 Ω , C_L = 10 pF (unless otherwise noted) (see Figure 9 and Figure 10)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|-------------------------------------|----------------------------------|----------------------------------|-----|--------------------|-----|------|
| t _{pd} ⁽²⁾ | Dn | D _A or D _B | | 149 | | ps |
| t _{PZH} , t _{PZL} | SEL | D _A or D _B | 0.5 | | 14 | ns |
| t _{PHZ} , t _{PLZ} | SEL | D _A or D _B | 0.9 | | 15 | ns |
| SEL to switch turn on time | | D _A or D _B | | 9 | 17 | ns |
| SEL to switch turn off time | D _A or D _B | D _A or D _B | | 5 | 18 | ns |
| t _{sk(o)} (3) | Dn (+)(-), DA | Dn (+)(-), DA(+)(-), DB(+)(-) | | 22 | 31 | ps |
| t _{sk(o)} | Dn (all), DnA | A(all), DnB(All) | | 19 | 23 | ps |
| t _{sk(p)} (4) | | | | 22 | 33 | ps |

- All typical values are at $V_{DD} = 2.5 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}$. The propagation delay is the calculated RC time constant of the typical ON-State resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
- Output skew between center port to any other port.
- Skew between opposite transitions of the same output in a given device |t_{PHL} t_{PLH}|



DYNAMIC CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 3.3 V ± 0.3 V, R_L = 50 Ω , C_L = 10 pF (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | TYP | UNIT |
|---------------------|-----------------------------|---|--------|------|
| X _{TALK} | Differential crosstalk | 825 MHz, 1.65Gbps, $R_L = 50 \Omega$, $C_L = 10 pF$, see Figure 11 | -34.67 | dB |
| O _{IRR} | Differential OFF isolation | 825 MHz, 1.65Gbps, $R_L = 50 \Omega$, $C_L = 10 pF$, see Figure 12 | -19.09 | dB |
| I _{LOSS} | Differential insertion loss | 825 MHz, 1.65Gbps, R_L = 50 Ω , C_L = 10 pF, seeFigure 13 | -2.84 | dB |
| I _{RETURN} | Differential return loss | 825 MHz, 1.65Gbps, R_L = 50 Ω , C_L = 10 pF, see Figure 13 | -9.43 | dB |
| DR | Data rate | | 2.20 | Gbps |
| BW | Differential bandwidth | | 1.10 | Ghz |

DYNAMIC CHARACTERISTICS

over recommended operating free-air temperature range, V_{DD} = 2.5 V ± 0.25 V, R_L = 50 Ω , C_L = 10 pF (unless otherwise noted)

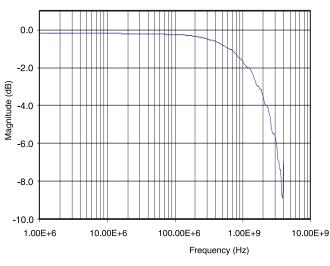
| | PARAMETER | TEST CONDITIONS | TYP | UNIT |
|---------------------|-----------------------------|--|--------|------|
| X _{TALK} | Differential crosstalk | 825 MHz, 1.65Gbps, R_L = 50 Ω , C_L = 10 pF, see Figure 7 | -34.94 | dB |
| O _{IRR} | Differential OFF isolation | 825 MHz, 1.65Gbps, $R_L = 50 \Omega$, $C_L = 10 pF$, see Figure 8 | -18.39 | dB |
| I _{LOSS} | Differential insertion loss | 825 MHz, 1.65Gbps, R_L = 50 Ω , C_L = 10 pF, see Figure 9 | -3.07 | dB |
| I _{RETURN} | Differential return loss | 825 MHz, 1.65Gbps, $R_L = 50 \Omega$, $C_L = 10 pF$, see Figure 9 | -9.56 | dB |
| DR | Data rate | | 2.20 | Gbps |
| BW | Differential bandwidth | | 1.10 | Ghz |

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TYPICAL PERFORMANCE



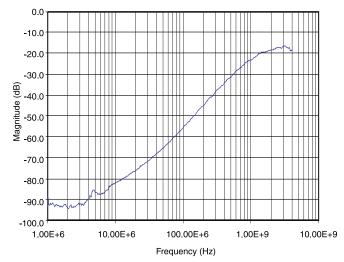
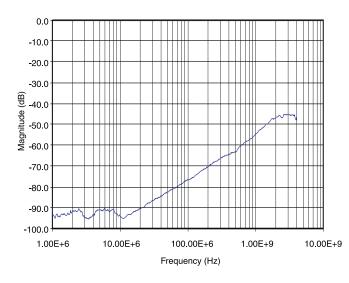


Figure 1. Differential Gain vs Frequency

Figure 2. Differential Off Isolation vs Frequency



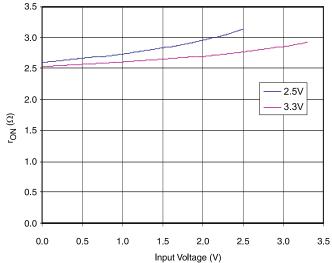


Figure 3. Differential Crosstalk vs Frequency

Figure 4. r_{ON} vs V_{COM} (Differential Switch)

Product Folder Link(s): TS3DV20812



APPLICATION INFORMATION

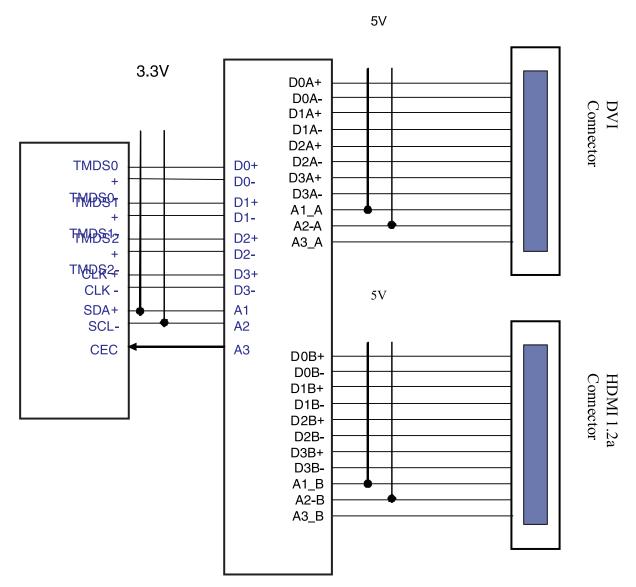


Figure 5. Typical Application Switching HDMI 1.2a and DVI

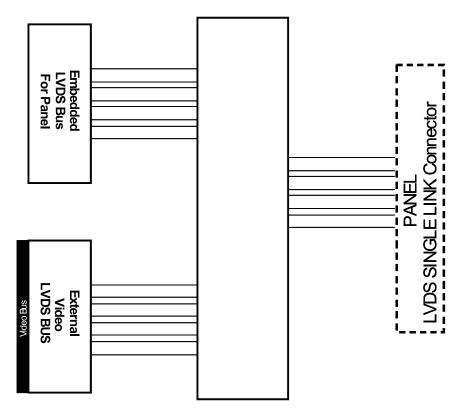
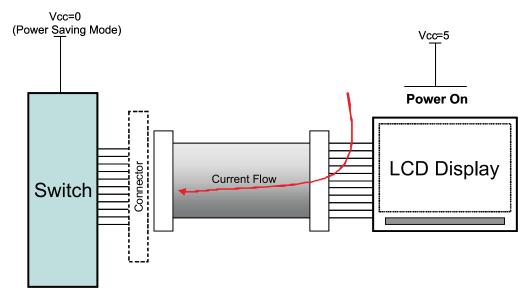


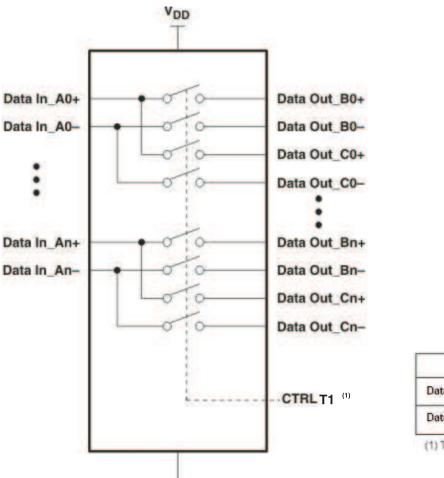
Figure 6. Typical Application for Dual LVDS



A. The switch already has I_{OFF} circuit and it will reduce the current flow leakage limit to 10 μ A maximum and it will prevent the damage from back drive current flow from the power-on circuit.

Figure 7. I_{OFF} (Back Drive Protection)

PARAMETER MEASUREMENT INFORMATION



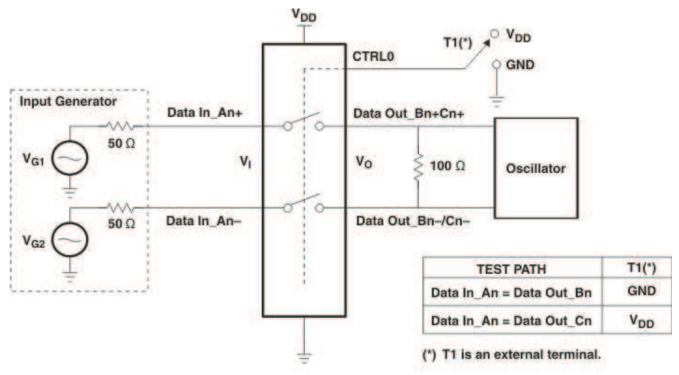
| T1(1) |
|-----------------|
| GND |
| V _{DD} |
| |

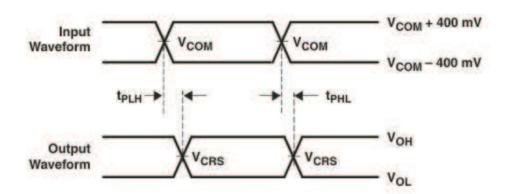
(1) T1 is an external terminal.

Figure 8. Differential Signaling Device

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PARAMETER MEASUREMENT INFORMATION (continued)

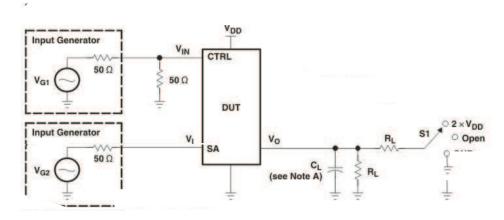




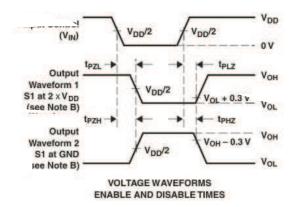
 V_{COM} = 1.5 V V_{CRS} is the cross-point of the differential signal. t_{sk} = $|t_{PLHn} - t_{PHLn}|$

Figure 9. Test Circuit for Propagation Delay and Intra-Pair Skew

PARAMETER MEASUREMENT INFORMATION (continued)



| TEST | V _{DD} | S1 | RL | VI | CL | V_{Δ} |
|------------------------------------|-----------------|-------------------|-------|-----|---------|--------------|
| t _{PLZ} /t _{PZL} | 3.3 V ±300 mV | 2×V _{DD} | 100 Ω | GND | No load | 0.3 V |
| 1Z/tpzH | 3.3 V ±300 mV | GND | 100 Ω | VDD | No load | 0.3 V |



A. CL includes probe and jig capacitance.

Figure 10. Test Circuit and Voltage Waveforms

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B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, ZO = 50 ohm, tr ≤ 2.5 ns, tf ≤ 2.5 ns

D. The outputs are measured one at a time, with one transition per measurement.

E. tPLZ and tPHZ are the same as tdis.

F. tPZL and tPZH are the same as ten.



PARAMETER MEASUREMENT INFORMATION (continued)

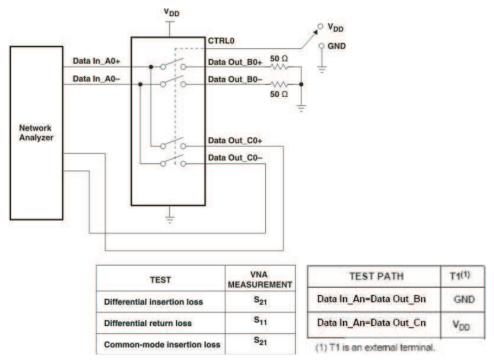
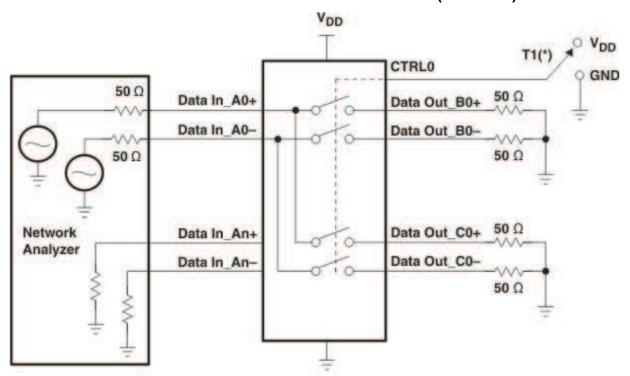


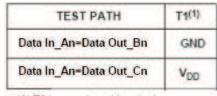
Figure 11. Differential Crosstalk Test Circuit



PARAMETER MEASUREMENT INFORMATION (continued)



(*) T1 is an external terminal.



(1) T1 is an external terminal.

Figure 12. Differential OFF Isolation Test Circuit

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PARAMETER MEASUREMENT INFORMATION (continued)

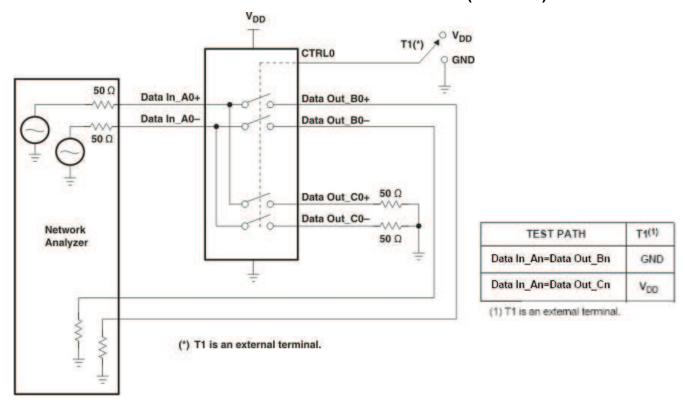


Figure 13. Differential Insertion Loss, Return Loss, and Common-Mode Insertion Loss Test Circuit



PACKAGE OPTION ADDENDUM

20-May-2013

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | _ | Pins | U | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|----------------------------|------------------|---------------------|--------------|----------------|---------|
| | (1) | | Drawing | | Qty | (2) | | (3) | | (4/5) | |
| TS3DV20812RHHR | ACTIVE | VQFN | RHH | 36 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-3-260C-168 HR | -40 to 85 | SY812 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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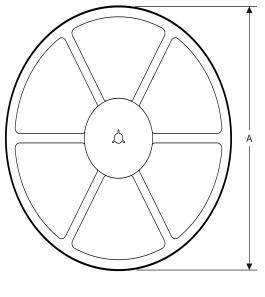
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PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

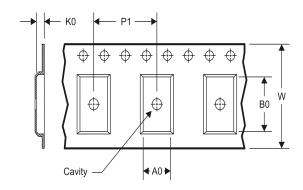
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TS3DV20812RHHR | VQFN | RHH | 36 | 2500 | 330.0 | 16.4 | 6.3 | 6.3 | 1.5 | 12.0 | 16.0 | Q2 |

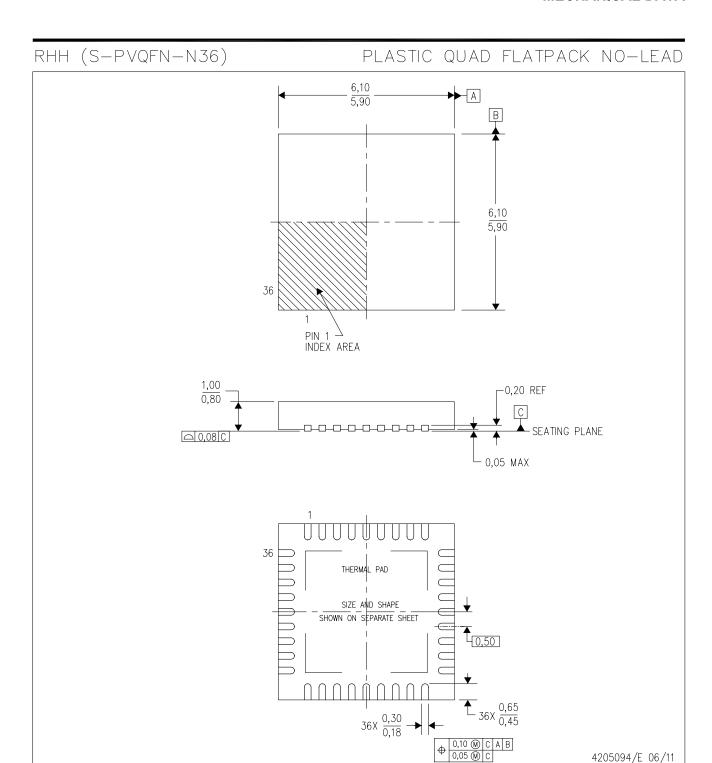
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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| TS3DV20812RHHR | VQFN | RHH | 36 | 2500 | 367.0 | 367.0 | 38.0 | |

4205094/E 06/11



NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) Package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.



RHH (S-PVQFN-N36)

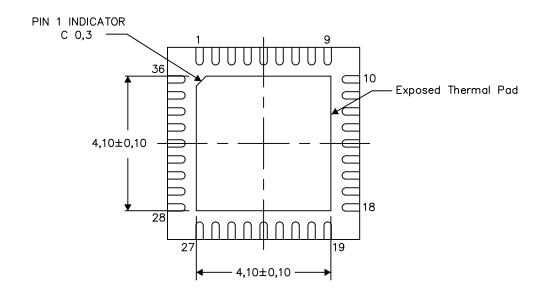
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

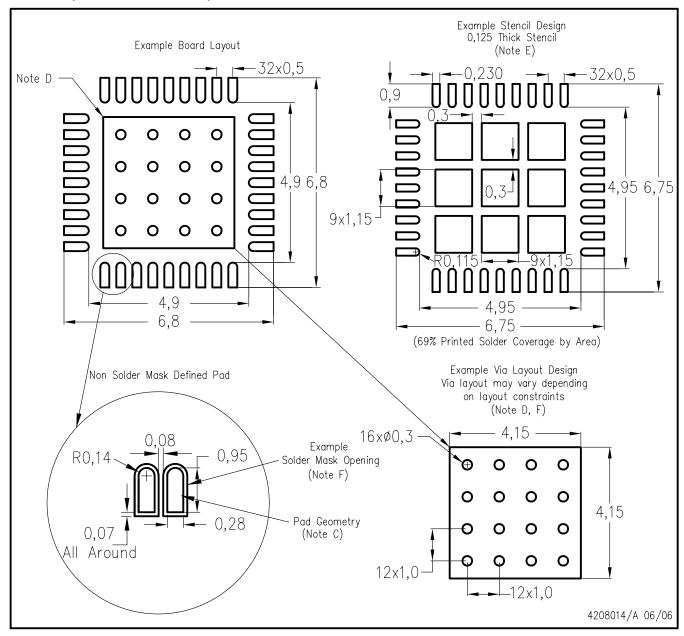
Exposed Thermal Pad Dimensions

4206362-3/L 10/12

NOTE: All linear dimensions are in millimeters



RHH (S-PQFP-N36)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



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